TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7MH4040FK

12-Stage Ripple-Carry Binary Counter

The TC7MH4040FK is an advanced high speed CMOS 12-stage ripple-carry binary counter fabricated with silicon gate C^2MOS technology.

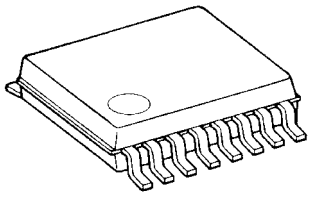
It achieves the high speed operation similar to equivalent bipolar schottky TTL while maintaining the CMOS low power dissipation.

Setting CLR to high resets the counter to low.

A negative transition on the $\overline{CK}$ input brings one increment into the counter.

This counter provides all divided output stages, and at Q12, a 1/4096 divided frequency will be output.

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.



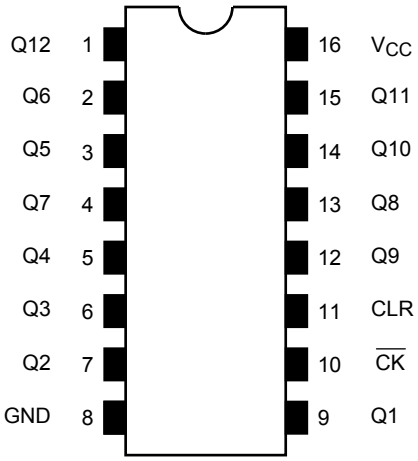
VSSOP16-P-0030-0.50

Weight: 0.02 g (typ.)

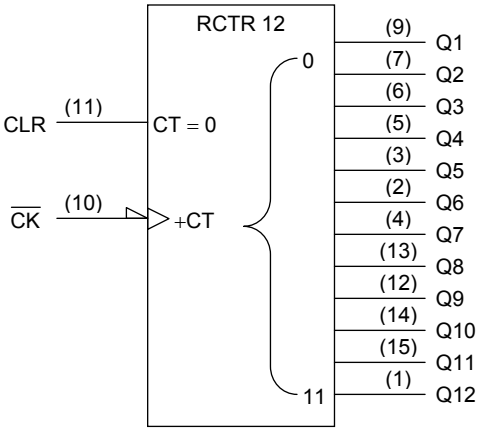
Features

- High speed: f_{max} = 210 MHz (typ.) (V_{CC} = 5 V)
- Low power dissipation: I_{CC} = 4 μA (max) (Ta = 25°C)
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays: $t_{pLH} \approx t_{pHL}$
- Wide operating voltage range: $V_{CC\ (opr)}$ = 2~5.5 V
- Low noise: V_{OLP} = 1.5 V (max)
- Pin and function compatible with 74HC4040

Pin Assignment (top view)



IEC Logic Level

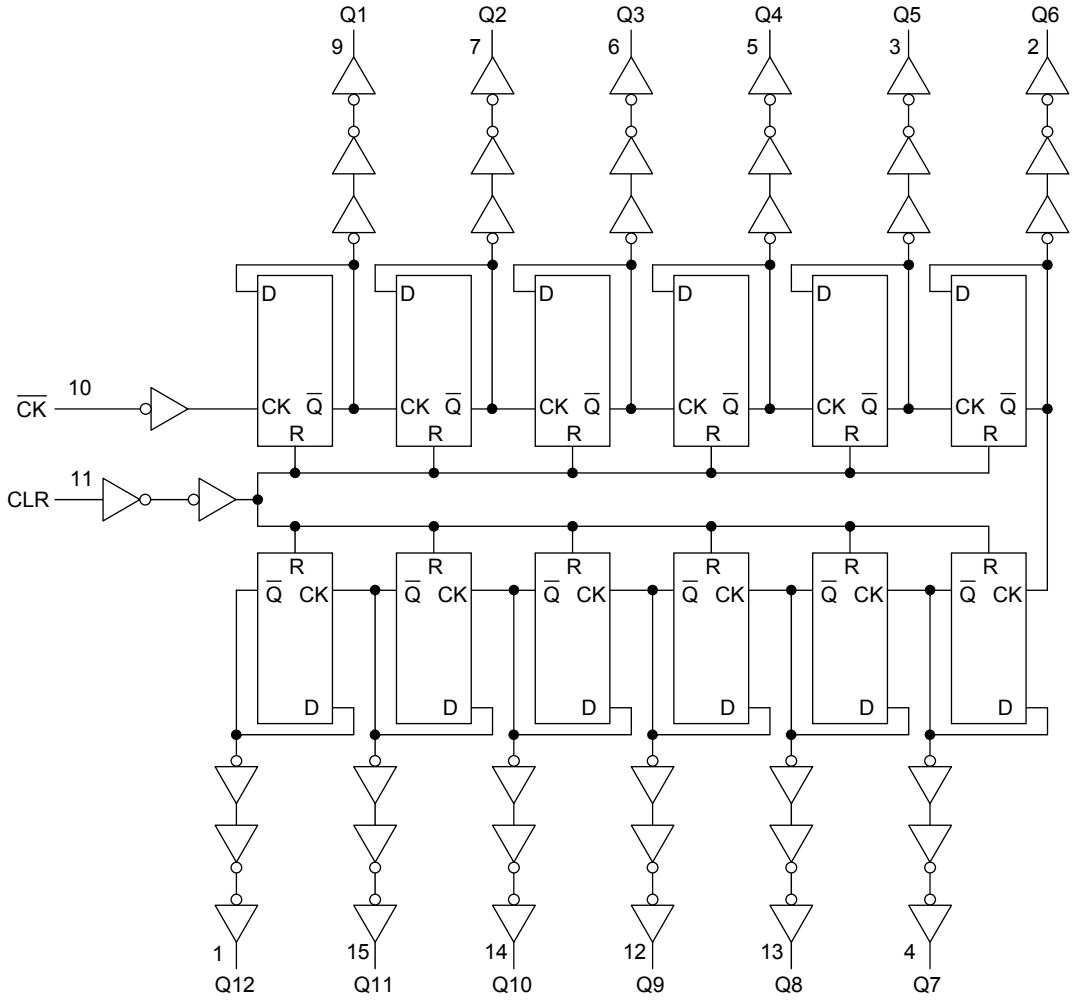


Truth Table

$\overline{CK}$	CLR	Outputs
X	H	All outputs = “L”
↑	L	No change
↓	L	Advance to next state

X: Don’t care

System Diagram



Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	−0.5~7.0	V
DC input voltage	V_{IN}	−0.5~7.0	V
DC output voltage	V_{OUT}	−0.5~V_{CC} + 0.5	V
Input diode current	I_{IK}	−20	mA
Output diode current	I_{OK}	±20	mA
DC output current	I_{OUT}	±25	mA
DC V_{CC}/ground current	I_{CC}	±100	mA
Power dissipation	P_D	180	mW
Storage temperature	T_{stg}	−65~150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, may lead to deterioration in IC performance or even destruction.
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2.0~5.5	V
Input voltage	V_{IN}	0~5.5	V
Output voltage	V_{OUT}	0~V_{CC}	V
Operating temperature	T_{opr}	−40~85	°C
Input rise and fall time	dt/dv	0~100 (V_{CC} = 3.3 ± 0.3 V)	ns/V
		0~20 (V_{CC} = 5 ± 0.5 V)	

Note: The operating ranges must be maintained to ensure the normal operation of the device.
Unused inputs must be tied to either V_{CC} or GND.

Electrical Characteristics

DC Characteristics

Characteristics		Symbol	Test Condition		Ta = 25°C			Ta = −40~85°C		Unit
				V_{CC} (V)	Min	Typ.	Max	Min	Max	
Input voltage	High level	V_{IH}	—	2.0	1.50	—	—	1.50	—	V
				3.0~5.5	V_{CC} × 0.7	—	—	V_{CC} × 0.7	—	
	Low level	V_{IL}	—	2.0	—	—	0.50	—	0.50	
				3.0~5.5	—	—	V_{CC} × 0.3	—	V_{CC} × 0.3	
Output voltage	High level	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA 2.0	1.9	2.0	—	1.9	—	V
				I_{OH} = −50 μA 3.0	2.9	3.0	—	2.9	—	
				I_{OH} = −50 μA 4.5	4.4	4.5	—	4.4	—	
				I_{OH} = −4 mA 3.0	2.58	—	—	2.48	—	
				I_{OH} = −8 mA 4.5	3.94	—	—	3.80	—	
	Low level	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA 2.0	—	0	0.1	—	0.1	
				I_{OL} = 50 μA 3.0	—	0	0.1	—	0.1	
				I_{OL} = 50 μA 4.5	—	0	0.1	—	0.1	
				I_{OL} = 4 mA 3.0	—	—	0.36	—	0.44	
				I_{OL} = 8 mA 4.5	—	—	0.36	—	0.44	
Input leakage current		I_{IN}	V_{IN} = 5.5 V or GND		0~5.5	—	—	±0.1	—	±1.0	μA
Quiescent supply current		I_{CC}	V_{IN} = V_{CC} or GND		5.5	—	—	4.0	—	40.0	μA

Timing Requirements (Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	Ta = 25°C		Ta = −40~85°C	Unit
			V_{CC} (V)	Typ.	Limit	Limit	
Minimum pulse width ($\overline{CK}$)	$t_{w(L)}$ $t_{w(H)}$	—	3.3 ± 0.3	—	5.0	5.0	ns
			5.0 ± 0.5	—	5.0	5.0	
Minimum pulse width (CLR)	$t_{w(H)}$	—	3.3 ± 0.3	—	5.0	5.0	ns
			5.0 ± 0.5	—	5.0	5.0	
Minimum removal time	t_{rem}	—	3.3 ± 0.3	—	5.0	5.0	ns
			5.0 ± 0.5	—	5.0	5.0	

AC Characteristics (Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = −40~85°C		Unit
			V_{CC} (V)	C_L (pF)	Min	Typ.	Max	Min	Max	
Propagation delay time ($\overline{CK}$ - Q1)	t_{pLH} t_{pHL}	—	3.3 ± 0.3	15	—	7.5	11.9	1.0	14.0	ns
				50	—	10.0	15.4	1.0	17.5	
			5.0 ± 0.5	15	—	4.8	7.3	1.0	8.5	
				50	—	6.3	9.3	1.0	10.5	
Propagation delay time (Q_n - Q_n + 1)	Δt_{pd}	—	3.3 ± 0.3	50	—	2.4	4.4	1.0	5.0	ns
			5.0 ± 0.5	50	—	1.6	3.1	1.0	3.5	
Propagation delay time (CLR - Q)	t_{pHL}	—	3.3 ± 0.3	15	—	8.3	12.8	1.0	15.0	ns
				50	—	10.8	16.3	1.0	18.5	
			5.0 ± 0.5	15	—	5.6	8.6	1.0	10.0	
				50	—	7.1	10.6	1.0	12.0	
Maximum clock frequency	f_{max}	—	3.3 ± 0.3	15	75	140	—	75	—	MHz
				50	55	80	—	50	—	
			5.0 ± 0.5	15	150	210	—	125	—	
				50	95	125	—	80	—	
Input capacitance	C_{IN}	—			—	4	10	—	10	pF
Power dissipation capacitance	C_{PD}	(Note)			—	21	—	—	—	pF

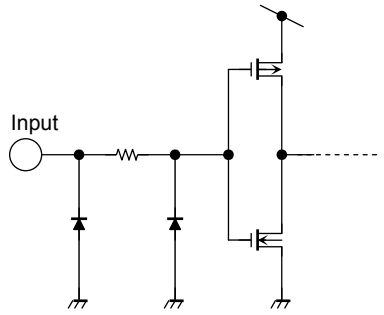
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.
Average operating current can be obtained by the equation:

$$I_{CC\ (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

Noise Characteristics (Input: $t_r = t_f = 3$ ns)

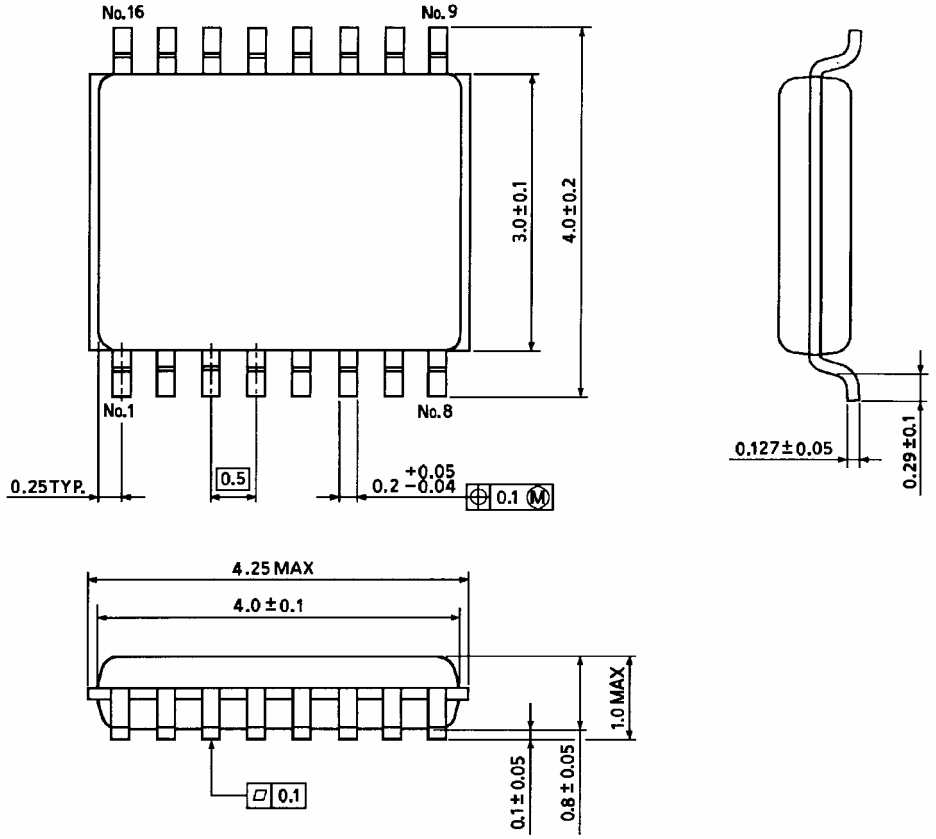
Characteristics	Symbol	Test Condition	Ta = 25°C			Unit
			V_{CC} (V)	Typ.	Limit	
Quiet output maximum dynamic V_{OL}	V_{OLP}	C_L = 50 pF	5.0	1.2	1.5	V
Quiet output minimum dynamic V_{OL}	V_{OLV}	C_L = 50 pF	5.0	−1.2	−1.5	V
Minimum high level dynamic input voltage V_{IH}	V_{IHD}	C_L = 50 pF	5.0	—	3.5	V
Minimum low level dynamic input voltage V_{IL}	V_{ILD}	C_L = 50 pF	5.0	—	1.5	V

Input Equivalent Circuit



Package Dimensions

VSSOP16-P-0030-0.50 Unit : mm



Weight: 0.02 g (typ.)

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20070701-EN GENERAL

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